



DMP4006SPSWQ

40V P-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	Rds(on) max	I _D Tc = +25°C
-40V	5.2mΩ @ V _{GS} = -10V	-115A
	7.9mΩ @ V _{GS} = -6V	-94A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

PowerDI5060-8/SWP (Type UX)

- Reverse-polarity protections
- BLDC motor controls
- Power-management functions
- Systems/load switches

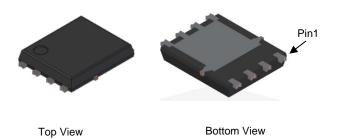
Features and Benefits

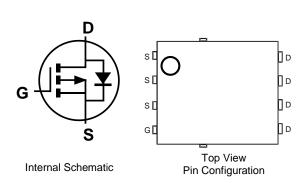
- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low On-Resistance
- Fast Switching Speed
- Wettable Flank for Improved Optical Inspections
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMP4006SPSWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)





Ordering Information (Note 4)

Part Number	Pookago	Packin	
	Package	Qty.	Carrier
DMP4006SPSWQ-13	PowerDI5060-8/SWP (Type UX)	2,500	Tape & Reel

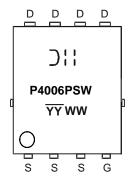
EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:



) | | = Manufacturer's Marking <u>P4</u>006PSW = Product Type Marking Code <u>YY</u>WW = Date Code Marking <u>YY</u>= Year (ex: 24 = 2024) WW = Week (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			VDSS	-40	V
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current (Note 6) V _{GS} = -10V	Steady State	Tc = +25°C Tc = +70°C	ID	-115 -92	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			ldм	-460	A
Maximum Body Diode Continuous Current			ls	-115	A
Pulsed Source Current (10µs Pulse, Duty Cycle = 1%)			lsм	-460	A
Avalanche Current (L = 0.1mH)			las	-72	А
Avalanche Energy (L = 0.1mH)			EAS	262	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

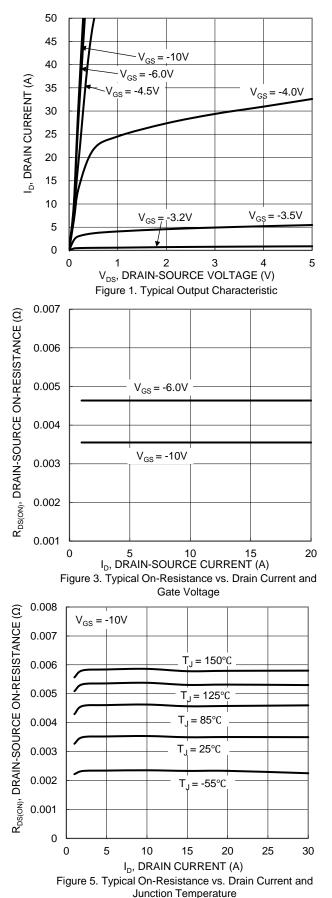
Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	3.4	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	36.5	°C/W
Total Power Dissipation (Note 6)	Tc = +25°C	PD	104	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	1.2	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

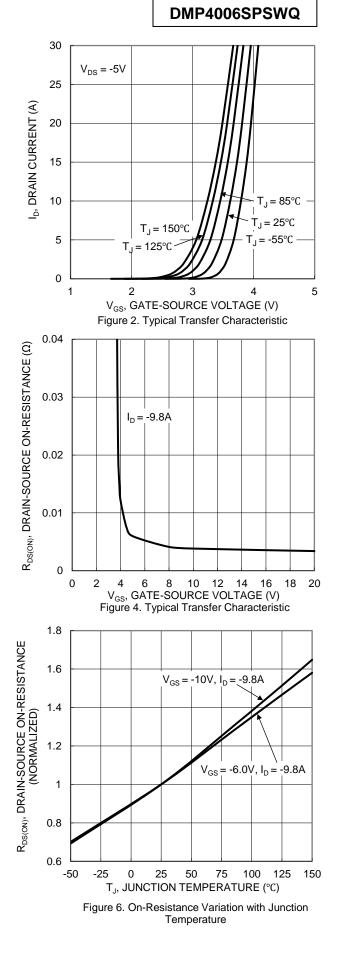
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	-40	_	_	V	V _{GS} = 0V, I _D = -250µA	
Zero Gate Voltage Drain Current	IDSS	_		-1	μA	$V_{DS} = -40V, V_{GS} = 0V$	
Gate-Source Leakage	lgss	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	VGS(TH)	-2.0		-3.0	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	
Static Drain-Source On-Resistance	Descent	_	3.6	5.2	mΩ	VGS = -10V, ID = -9.8A	
Static Drain-Source On-Resistance	RDS(ON)	_	4.5	7.9	1115.2	$V_{GS} = -6V, I_D = -9.8A$	
Diode Forward Voltage	Vsd	_	-0.7	-1	V	$V_{GS} = 0V$, $I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	6855	_		$V_{DS} = -20V, V_{GS} = 0V$ f = 1MHz	
Output Capacitance	Coss	_	883	_	pF		
Reverse Transfer Capacitance	Crss	_	526	_			
Gate Resistance	Rg	_	7.8	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = -10V)	Qg	_	162			V _{DS} = -20V, I _D = -9.8A	
Gate-Source Charge	Qgs	_	28	_	nC		
Gate-Drain Charge	Q _{gd}	_	38	_			
Turn-On Delay Time	t _{D(ON)}	_	28	_		$V_{GS} = -10V, V_{DD} = -20V,$ $R_G = 6\Omega, I_D = -9.8A$	
Turn-On Rise Time	tR	_	32	_	1		
Turn-Off Delay Time	tD(OFF)		469	_	ns		
Turn-Off Fall Time	tF		228				
Reverse Recovery Time	t _{RR}	_	44	_	ns	IF = -9.8A, di/dt = -100A/µs	
Reverse Recovery Charge	Qrr	_	48	_	nC	I _F = -9.8A, di/dt = -100A/µs	

5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
6. Thermal resistance from junction to soldering point (on the exposed drain pad).
7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to product testing. Notes:

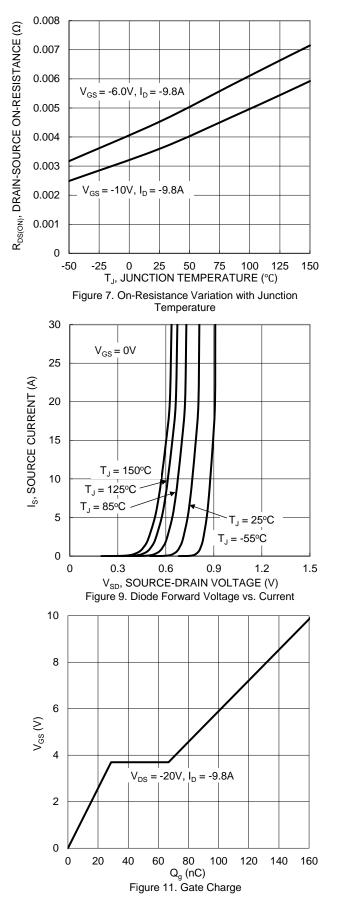


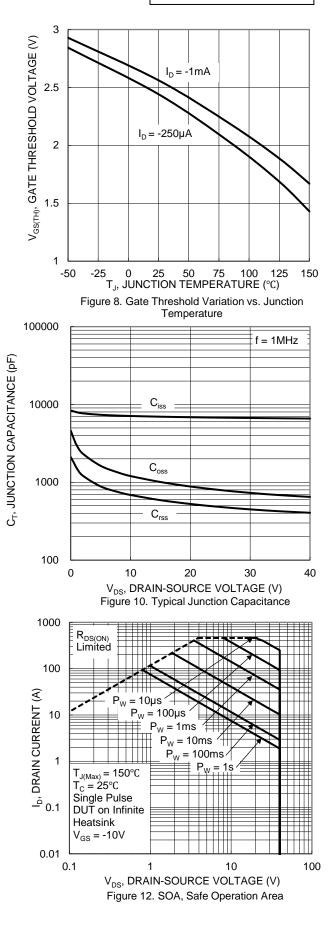




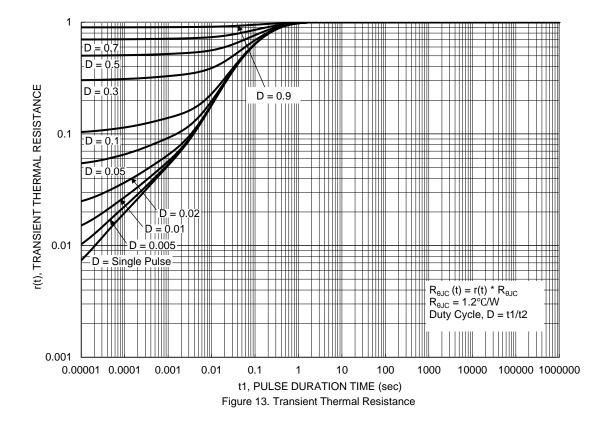


DMP4006SPSWQ





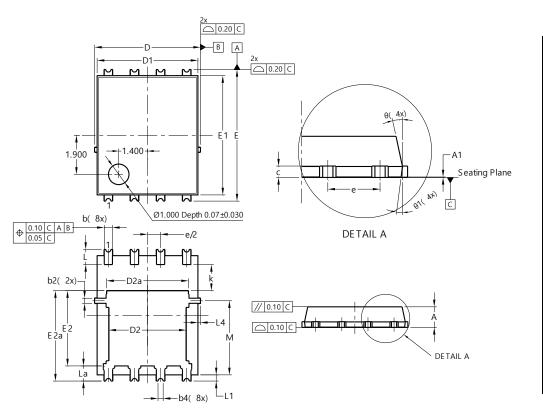






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



PowerDI5060-8/SWP (Type UX)

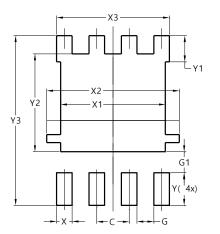
(Type UX) Dim Min Max Тур 0.90 Α 1.10 1.00 0.05 A1 0 --0.41 0.30 0.50 b b2 0.35 0.25 0.20 b4 0.25REF 0.230 0.330 0.277 С D 5.15 BSC D1 4.70 5.10 4.90 D2 3.76 3.56 3.96 D2a 3.78 4.18 3.98 Ε 6.40 BS 6.00 E1 5.60 5.80 E2 3.46 3.86 3.66 E2a 4.195 4.595 4.395 1.27BSC е 1.05 k -----0.735 L 0.635 0.835 0.735 La 0.635 0.835 0.300 L1 0.200 0.400 L4 0.025 0.225 0.125 М 3.205 4.005 3.605 θ 10° 12° 11° θ1 6° 8° 7° All Dimensions in mm

PowerDI5060-8/SWP

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8/SWP (Type UX)



Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	4.100		
X2	5.190		
X3	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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